# **High Voltage Switching Diode**

## **Features**

• These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

## **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V <sub>R</sub>	250	V
Peak Forward Current	I <sub>F</sub>	200	mA
Peak Forward Surge Current	I <sub>FM(surge)</sub>	625	mA

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Forward Power Dissipation, FR–5 Board (Note 1) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>F</sub>	400 3.2	mW mW/°C
Thermal Resistance, Junction-to-Case	$R_{\theta JL}$	174	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	492	°C/W
Junction and Storage Temperature Range	$T_{J_1}T_{stg}$	-55 to +150	ç

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.



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SOD-123 CASE 425 STYLE 1

### MARKING DIAGRAM



JS = Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

## **ORDERING INFORMATION**

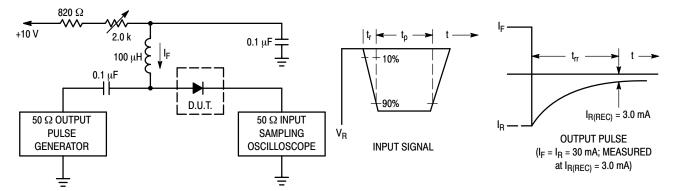
Device	Package	Shipping <sup>†</sup>
MMSD103T1G	SOD-123 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Voltage Leakage Current (V <sub>R</sub> = 200 V) (V <sub>R</sub> = 200 V, T <sub>J</sub> = 150°C)	I <sub>R</sub>	- -	1.0 100	μΑ
Reverse Breakdown Voltage (I <sub>BR</sub> = 100 μA)	V <sub>(BR)</sub>	250	-	V
Forward Voltage $(I_F = 100 \text{ mA})$ $(I_F = 200 \text{ mA})$	V <sub>F</sub>	- -	1000 1250	mV
Diode Capacitance (V <sub>R</sub> = 0, f = 1.0 MHz)	C <sub>D</sub>	-	5.0	pF
Reverse Recovery Time (I <sub>F</sub> = I <sub>R</sub> = 30 mA, R <sub>L</sub> = 100 $\Omega$ )	t <sub>rr</sub>	-	50	ns



Notes: 1. A 2.0  $k\Omega$  variable resistor adjusted for a Forward Current (I\_F) of 30 mA.

2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 30 mA.

3. t<sub>p</sub> » t<sub>rr</sub>

Figure 1. Recovery Time Equivalent Test Circuit

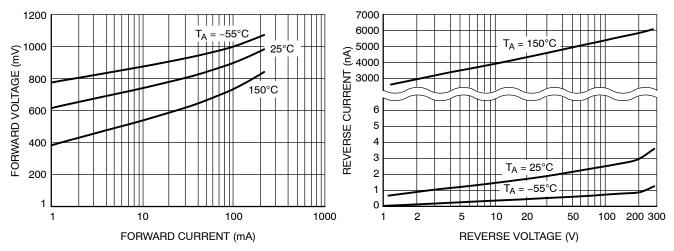


Figure 2. Forward Voltage

Figure 3. Reverse Leakage

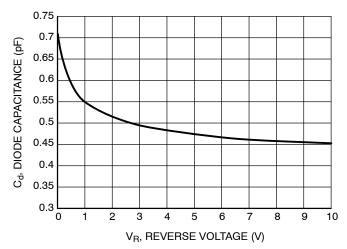
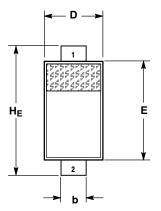
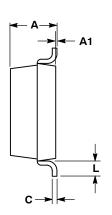


Figure 4. Diode Capacitance

## PACKAGE DIMENSIONS

SOD-123 CASE 425-04 ISSUE E





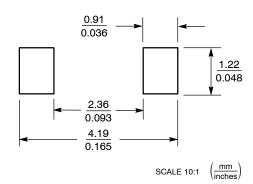
#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
  Y14.5M. 1982.
- 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.94	1.17	1.35	0.037	0.046	0.053
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.51	0.61	0.71	0.020	0.024	0.028
С			0.15			0.006
D	1.40	1.60	1.80	0.055	0.063	0.071
E	2.54	2.69	2.84	0.100	0.106	0.112
HE	3.56	3.68	3.86	0.140	0.145	0.152
L	0.25		1	0.010		

STYLE 1: PIN 1. CATHODE 2. ANODE

## **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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